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High-temperature thermoelectric properties of Naand W-Doped Ca₃Co₄O₉ system

Uzma Hira, ab Li Han, kion Norrman, Dennis Valbjørn Christensen, Nini Pryds and Falak Sher ka

The detailed crystal structures and high temperature thermoelectric properties of polycrystalline $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples have been investigated. Powder X-ray diffraction data show that all samples are phase pure, with no detectable traces of impurity. The diffraction peaks shift to lower angle values with increase in doping (x), which is consistent with larger ionic radii of Na^+ and W^{6+} ions. X-ray photoelectron spectroscopy data reveal that a mixture of Co^{2+} , Co^{3+} and Co^{4+} valence states are present in all samples. It has been observed that electrical resistivity (ρ), Seebeck coefficient (S) and thermal conductivity (κ) are all improved with dual doping of Na and Na in $Ca_3Co_4O_9$ system. A maximum power factor (PF) of 2.71×10^{-4} W m⁻¹ K⁻² has been obtained for x = 0.025 sample at 1000 K. The corresponding thermoelectric figure of merit (zT) for x = 0.025 sample is calculated to be 0.21 at 1000 K, which is ~ 2.3 times higher than zT value of the undoped sample. These results suggest that Na and Na dual doping is a promising approach for improving thermoelectric properties of Na cases Na system.

Introduction

Thermoelectric (TE) power generation from waste heat is considered as a promising renewable energy technology.^{1,2} TE devices convert thermal energy into electricity *via* the Seebeck effect, and electrical power into solid state refrigeration *via* the Peltier effect.³ In order to convert waste heat into electrical energy efficiently, good TE materials with high values of dimensionless figure of merit (*zT*) are required:⁴

$$zT = \frac{S^2T}{\rho\kappa} \tag{1}$$

where S (V K⁻¹) is the Seebeck coefficient, T (K) is the absolute temperature, ρ (Ω m) is the electrical resistivity, and κ (W m⁻¹ K⁻¹) is the thermal conductivity.

For practical high waste heat to electricity conversion efficiency devices, zT > 1 is an essential prerequisite. Therefore robust TE materials with large thermoelectric power factor: PF = S^2/ρ and smaller thermal conductivity are required. In addition, TE materials must be stable in air at high operating temperatures over a long period of time and should be made of earth-abundant low cost elements. Conventional thermoelectric materials such as Bi₂Te₃ ($T_{\rm max} = 550$ K), SiGe ($T_{\rm max} > 1300$ K expensive and oxidation sensitive) and half-Heusler compounds ($T_{\rm max} = 850$ K) do not meet all requirements for high

temperature thermoelectric applications.5-7 Transition metal oxides are promising candidates and have been explored for their potential applications in high temperature thermoelectric devices. A number of transition metal oxides such as CaMnO₃,² Al-doped ZnO8 and Ta-doped SrTiO3 (ref. 9) show good thermoelectric properties and are stable in air at high temperatures of around 1000 K. Moreover, metal oxides can be synthesized from non-toxic and inexpensive precursors 10 and can possibly segmented with non-oxide materials in TE modules to increase the efficiency of devices.11 Consequently, significant research efforts have been recently devoted to the development of thermoelectric generators (TEGs) for automotive applications.12 Among the transition metal oxides, misfit-layered cobaltites such as Na_xCoO₂,¹³ Ca₃Co₄O₉,¹⁴ CuAlO₂ (ref. 15) and Bi₂Sr₂- Co_2O_x (ref. 16) are considered to be promising p-type thermoelectric oxides for high temperature applications. Misfit-layered Ca₃Co₄O₉ (abbreviated as C-349 in the following text) cobaltite is especially an interesting candidate material due to its good thermoelectric performance ($zT \sim 0.83$ at 973 K for single crystal $Ca_3Co_4O_9$ and ~ 0.64 at 1073 K for heavily doped polycrystalline Ca₃Co₄O_{9+δ} materials with metallic nanoinclusions), and its high thermal and chemical stabilities in air.17,18

 $\text{Ca}_3\text{Co}_4\text{O}_9$ cobaltite has a monoclinic misfit structure with superspace group (X2/m(0b0)s0) crystal symmetry. C-349 compound is generally described as $[\text{Ca}_2\text{CoO}_3][\text{CoO}_2]_{1.61}$ and its high performance is linked with its unique layered crystal structure. It consists of two subsystems: a NaCl-type rocksalt (RS) Ca_2CoO_3 layer [subsystem 1] sandwiched between two CdI2-type (H) CoO_2 hexagonal layers [subsystem 2]. These two subsystems share the same a, c and β lattice parameters, and

^aDepartment of Chemistry and Chemical Engineering, SBA School of Science and Engineering, Lahore University of Management Sciences (LUMS), Lahore, Pakistan. E-mail: fsher@lums.edu.pk; Tel: +92 42 3560 8131

^bDepartment of Energy Conversion and Storage, Technical University of Denmark, Risø DTU, Denmark. E-mail: nipr@dtu.dk; Tel: +45 46 775752

stack alternatively along the c axis. The mismatch of two unit cells results in dissimilar lattice parameters along the b axis i.e., b_1 [subsystem 1] and b_2 [subsystem 2] with a ratio b_1 (RS)/ b_2 (H) \sim 1.61. The Ca₂CoO₃ (RS)-type block is an insulating layer whereas CoO₂ (H) sheet is conductive.²⁰

Recently, a number of research studies have focused on improving the TE performance of C-349 polycrystalline materials by using innovative synthesis methods such as spark plasma sintering (SPS),21 hot pressing,22 auto-combustion synthesis and solgel based electrospinning followed by SPS^{23,24} etc. Chemical substitution of alternate metal cations at both Ca- and Co-sites of Ca₃Co₄O₉ is another approach that has been used to fine tune the electrical and thermal transport properties of TE oxides. These studies include partial substitution of Na, Bi, Y, Ag, Nd, Sr and Pb ions²⁵⁻³² at Ca-sites, which adjusts the carrier concentration without changing much the band structure of materials, and substitution of Fe, Mn, Cu, Ti, Ga, Mo, W and In ions³³⁻³⁸ at Cosites with significant changes in the band structure and transport mechanism. In another research work, it was reported that doping of Na ions at Ca-sites resulted in decrease of electrical resistivity and as a consequence increase of thermoelectric power factor to ${\sim}5.5~\times~10^{-4}~W~m^{-1}~K^{-2}$ at 1000 K, though thermal conductivity (κ) of these samples was still too high (4.0 W m⁻¹ K^{-1}), impeded the further improvement of zT values.²⁵ On the other hand, high valence 4d and 5d transition metal-doped C-349 samples exhibited much smaller thermal conductivity with reasonably good zT values.39 There are some research studies on simultaneous substitution of two different metal cations at Ca- and Co-sites in C-349 system with significant improvement in TE properties with zT values of \sim 0.20–0.25. 40-42 However, there are no reports published on dual doping of Na and W metals in Ca₃Co₄O₉ cobaltite as yet.

This prompted us to prepare a series of $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}$ - $W_x\text{O}_9$ ($0 \le x \le 0.075$) oxides by the conventional solid-state reaction method, and investigate their structural and high-temperature thermoelectric properties. We anticipated that Na and W dual doping in C-349 system would increase the Seebeck coefficient and electrical conductivity while thermal conductivity would decrease due to the W substitution. In this way, we expected to achieve much better zT values for these materials.

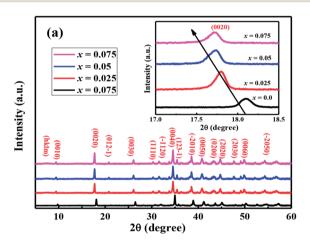
2. Experimental

Polycrystalline samples of $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) series were prepared by the conventional solid-state reaction method. Stoichiometric quantities of $CaCO_3$ ($\ge 99.5\%$; Sigma-Aldrich), Co_3O_4 ($\ge 99.5\%$; Sigma-Aldrich) and $Na_2WO_4 \cdot 2H_2O$ ($\ge 99.5\%$; Sigma-Aldrich) were ground, thoroughly mixed and pressed into pellets and initially sintered at 700 °C for 8 h. Sintered pellets were reground, pressed into pellets again and sintered twice at 900 °C for 8 h, with intermediate grinding and pelletizing, at a heating rate of $10 \, ^{\circ}C$ min $^{-1}$ in air and slowly cooled down to room temperature.

Powder X-ray diffraction (XRD) data were collected in 2 theta range $5^{\circ} \leq 2\theta \leq 60^{\circ}$ with a step size of 0.02° using a Bruker D8 Advanced diffractometer at room temperature with Cu K_{α} ($\lambda=1.5406$ Å) radiation. Rietveld refinements of XRD data were

performed using a computer program JANA2006.⁴³ Surface morphology of samples was studied using a FEI Nova NanoSEM 450 scanning electron microscope (SEM). X-ray photoelectron spectroscopy (XPS, Thermo Electron Limited, Winsford, UK) was used to examine the oxidation states of Co and W ions in C-349 based materials. Analyses were performed using a monochromatic (Al-K α) X-ray source at room temperature with a takeoff angle of 90° from the surface plane. High-resolution Co 2p and W 4f XPS spectra were recorded using 50 eV detector pass energy and 10 scans. The binding energies were assessed by referencing to the Au 4f peak at 84.0 eV. Hall measurements were carried out at room temperature by using van der Pauw method with a (5.08 T) superconducting magnet.

The Seebeck coefficient (S) and electrical resistivity (ρ) were simultaneously measured from room temperature to 1000 K with an ULVAC-RIKO ZEM3 under a low pressure helium atmosphere. The thermal diffusivity (α) was measured with (NETZSCH LFA-457) laser flash system under vacuum. The heat capacity (C_p) was estimated using temperature independent Dulong–Petit law. The thermal conductivity (κ) was calculated



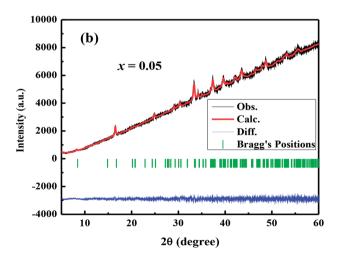


Fig. 1 (a) XRD patterns of $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples; inset: the shift of (0020) peaks with change of doping content (x). (b) Rietveld refined XRD pattern of $Ca_{2.9}Na_{0.1}Co_{3.95}W_{0.05}O_9$ sample.

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Table 1 Crystallographic parameters for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ (0 $\leq x \leq$ 0.075) samples obtained from the Rietveld refinement analysis of powder X-ray diffraction data^a

Composition Ca _{3-2x} Na _{2x} Co _{4-x} W _x O ₉	x = 0.0	x = 0.025	x = 0.05	x = 0.075
Lattice parameters				
a (Å)	4.8229(2)	4.8231(5)	4.8268(5)	4.8335(2)
b_1 (Å)	4.5453(2)	4.5690(8)	4.5671(9)	4.5689(8)
b_2 (Å)	2.8215(3)	2.8134(3)	2.8103(8)	2.8145(3)
c (Å)	10.8215(9)	10.8394(2)	10.8557(2)	10.8498(2)
β (deg)	98.807(3)	98.329(1)	98.582(8)	98.396(4)
$\delta \left(b_1/b_2 \right)$	1.61	1.62	1.62	1.62
$V_1 \left(\mathring{\mathbf{A}} \right)^3$	234.7(4)	236.3(4)	236.6(4)	237.0(4)
$V_2 (\mathring{A})^3$	145.2(7)	145.5(7)	145.6(7)	146.0(7)
Reliability factors				
R_{wp} (%)	3.99	2.94	2.41	1.97
$R_{\rm p}$ (%)	3.25	2.34	1.93	1.51
GOF	3.29	2.44	1.84	1.97

using equation ($\kappa = \alpha \cdot \rho \cdot C_p$), where C_p , ρ and α are the specific heat capacity, mass density and thermal diffusivity, respectively. Mass density of the samples was measured by Archimedes method using water with a few drops of surfactant.

^a b_1 and b_2 are the b-axis lattice parameter for $[Ca_2CoO_3]$ and $[CoO_2]$ subsystems, respectively.

3. Result and discussion

3.1. Crystal structure and surface morphology

The crystal structures of $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples were analyzed by collecting the powder X-ray diffraction data at room temperature. The diffraction peaks in XRD patterns of all samples (Fig. 1(a)) are identical to the standard JCPDS card (21-139) of C-349 system,⁴⁴ indicating the formation

of phase pure compounds. The enlarged portions of (0020) diffraction peaks are presented in inset of Fig. 1(a) to illustrate the effect of Na and W dual doping on C-349 crystal structure. It can be clearly seen that the diffraction peaks shift to lower 2θ values with increase in doping content (x). The XRD data was Rietveld refined using a computer program JANA 2006 (ref. 43) in the superspace group X2/m(0b0)s0 and the resulting structural parameters are listed in Table 1. The refined XRD pattern of x = 0.05 sample is shown in Fig. 1(b), as an example. It can be seen from Table 1 and Fig. 2 that the lattice parameters a, b_1 , c and unit cell volumes (V_1 and V_2) all slightly increase with increase in doping content (x), which is consistent with the observed shifting of diffraction peaks to lower 2θ values.

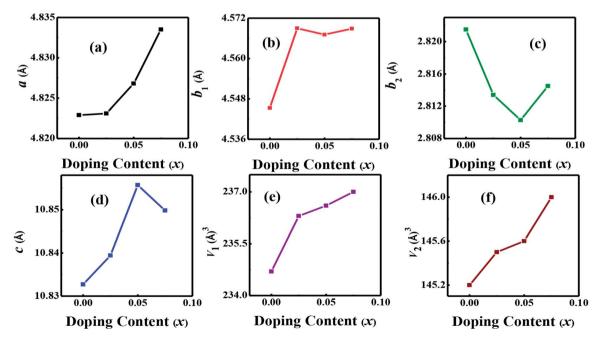


Fig. 2 Structural parameters a, b_1 , b_2 , c, V_1 and V_2 as a function of doping content (x) for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) series.

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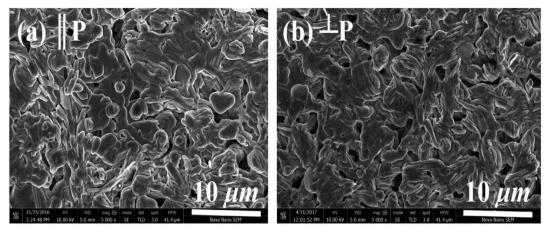


Fig. 3 SEM micrographs of (a) parallel ($\parallel P$) and (b) perpendicular ($\perp P$) surfaces for x=0.05 sample

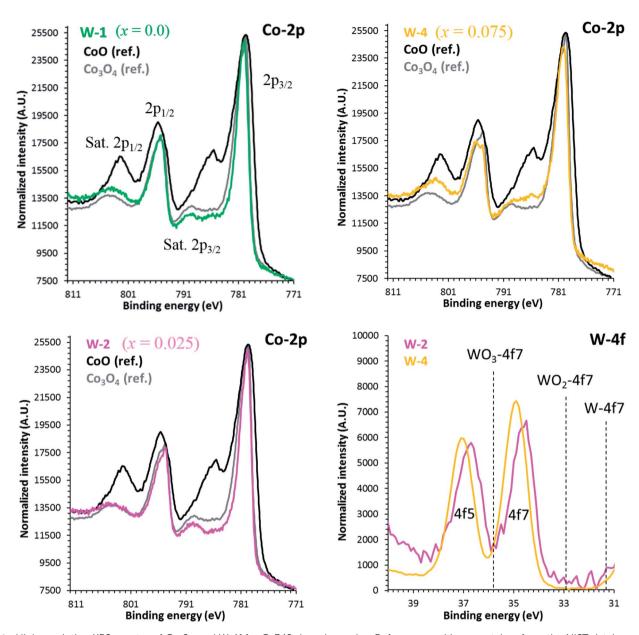
However, the values of b_2 decrease with increase in doping suggesting that there is an increase of crystallographic distortion. This trend in the lattice parameters with doping is in agreement with the observation that ionic radii of Na⁺ (1.02 Å) and W^{6+} (0.6 Å) ions are larger than the corresponding Ca^{2+} (1.0 \mathring{A}) and Co^{3+} (0.545 \mathring{A})/ Co^{4+} (0.53 \mathring{A}) ions in the six coordination number, 45 respectively. The quality factors like GOF, $R_{\rm wp}$ and $R_{\rm p}$ (Table 1) are all within the acceptable statistical range, suggesting that the Rietveld refinements of samples are reliable.

The morphology of samples in two different directions, parallel ($\|p$) and perpendicular ($\perp p$), to the pellets pressure axis (Fig. 3) were studied by the scanning electron microscopy in order to find out if there is any micro-dimensional anisotropy in these layered materials. The grain morphology in both parallel (||p) and perpendicular $(\perp p)$ directions of the pressure axis seems to be almost identical, suggesting that there is no or negligible anisotropy that can be observed on a micrometer scale. The SEM images show the plate-like crystal grains morphology, which is a typical feature of materials, including C-349 system, that are prepared by the conventional solid state chemistry method. 46 Close inspection of the SEM micrograph for x = 0.025 sample reveals that crystal grains are larger (\sim 2.52 µm) and more compact than crystal grains of other samples (0.83-1.45 µm). The measured densities for all samples are in the range \sim 86-94% of the theoretical density (Table 2).

The binding energies of Co 2p and W 4f sub-shells of selected samples were estimated from the high resolution XPS measurements as shown in Fig. 4. As reported elsewhere, the XPS spectrum of Co 2p splits into two parts, Co $2p_{3/2}$ and $2p_{1/2}$ with an intensity ratio of approximately (2:1) due to the spinorbit coupling.47 The line shapes of both Co 2p_{3/2} and 2p_{1/2} spectra are similar to the reported results in literature.48 The main peaks corresponding to the Co 2p3/2 energy are located at 778.8 eV, 779.69 eV and 781.0 eV corresponding to x = 0.0, 0.025and 0.075 samples, respectively. Shake-up satellite peaks due to the metal-to-ligand charge transfer processes at higher binding energies than the $2p_{3/2}$ and $2p_{1/2}$ main peaks are also detected. The observed variations in Co 2p_{3/2} binding energies can be explained by the larger electronegativity of tungsten (2.36, Pauli scale) than cobalt (1.88, Pauli scale).49 With careful analysis of XPS data, we can predict that Co ions have three types of valence states: Co²⁺, Co³⁺ and Co⁴⁺ in all samples. However, the average valence state of Co is most likely between 3+ and 4+ as reported elsewhere.50,51 The observed increase in binding energies of Co $2p_{3/2}$ peaks suggests that the relative population of Co³⁺ ions is decreasing with increase in doping. The 4f₅ and 4f₇ peaks for W ions closely resemble with the reference peaks of WO3, indicating that they are present in W⁶⁺ valence states in all samples.

Table 2 Average grain size, bulk density, carrier mobility ($\mu_{300 \text{ K}}$), activation energy (E_a) and important thermoelectric parameters are listed

Composition $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$	x = 0.0	x = 0.025	x = 0.05	x = 0.075
Average grain size (μm)	$0.83~(\pm 0.002)$	$2.52\ (\pm0.09)$	$1.45~(\pm 0.005)$	$0.80~(\pm 0.007)$
Density (g cm ⁻³)	$3.801\ (\pm0.02)$	4.09 (0.045)	$3.98\ (\pm0.032)$	$3.844\ (\pm0.068)$
Theoretical density (g cm ⁻³)	4.37	4.37	4.38	4.39
Relative density (%)	86.27	94.67	90.87	87.56
Mobility, $\mu_{300 \text{ K}} (\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1})$	0.64	0.82	0.74	0.65
$ ho_{T=1000\mathrm{K}} imes10^{-5}ig(\Omega\mathrm{m}ig)$	23.98	13.07	16.09	27.54
$E_{\rm a}$ (meV)	49	98	103	76
$S_{T = 1000 \text{ K}} (\mu \text{V K}^{-1})$	174.99	182.72	192.67	215.99
$\kappa_{T = 1000 \text{ K}} (\text{W m}^{-1} \text{ K}^{-1})$	1.367	1.266	1.323	1.343
$zT_{T=1000\mathrm{K}}$	0.093	0.21	0.18	0.13



ig. 4 High resolution XPS spectra of Co 2p and W 4f for C-349 doped samples. Reference positions are taken from the NIST database.

3.2. Thermoelectric properties

The temperature dependent electrical resistivities, $\rho(T)$, as a function of Na and W co-doping (x) are shown in Fig. 5(a). The $\rho(T)$ curve for x=0.0 sample exhibits a semiconducting like behavior $(\mathrm{d}\rho/\mathrm{d}T<0)$ from room temperature to around 500 K, and then shows a transition to metallic like behavior $(\mathrm{d}\rho/\mathrm{d}T>0)$ from 600 K onwards. This kind of behavior in resistivity of C-349 system has been previously attributed to the spin-state transition, ⁵² removal of oxygen atoms from porous layered cobaltites ³⁸ and structural distortion in Ca₂CoO₃ sheets. ⁵³ On the other hand, all doped samples show metallic behavior at low temperatures before showing a transition to semiconducting behavior above 400 K. The absolute values of resistivity at 1000 K for x=0.025 and 0.05 samples are smaller than that of undoped sample, but higher for x=0.075. This shows that dual

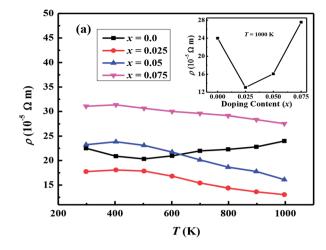
doping of small amounts of Na and W has beneficial effect on resistivity of our samples.

We can describe the high temperature electrical resistivity of cobaltites using the small polaron hopping model,⁵⁴ which is given by the following relation:

$$\rho(T) = \rho_0 T \exp\left(\frac{E_a}{k_B T}\right) \tag{2}$$

where ρ_0 is a constant factor called the residual resistivity, $k_{\rm B}$ is the Boltzmann constant and $E_{\rm a}$ is the activation energy of electrical conductivity for polaron hopping.

The linear fits of $\ln(\rho/T)$ *versus* 1/*T* above 600 K, as shown in Fig. 5(b), suggest that the small polaron hopping model applies well to the electrical resistivity of these materials. The slopes of straight lines (E_a/k_B) were used to estimate the activation



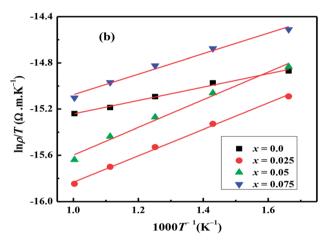


Fig. 5 (a) Electrical resistivity (ρ) for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples as a function of temperature; inset shows doping content (x) dependence of ρ at 1000 K. (b) Linear fits of $\ln(\rho/T)$ vs. 1000/T for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples.

energies for all samples as listed in Table 2. It has been observed that $E_{\rm a}$ values for doped samples are relatively higher than the pristine C-349 system. This suggests that energy demand for carriers to jump from the top of valence band to the bottom of conduction band, in general, increases with doping in our samples. However, this variation could also be due to the creation of some in-gap states which would change with doping. As discussed elsewhere, hoping of carriers occurs between ${\rm Co^{3^+}}$ and ${\rm Co^{4^+}}$ in ${\rm CoO_2}$ layer and as a consequent the ratio of ${\rm Co^{3^+}}$ and ${\rm Co^{4^+}}$ ions directly affects the hopping distance in these materials. 55 We anticipate that concentration of ${\rm Co^{4^+}}$ ions would decrease with increase in doping of ${\rm W^{6^+}}$ ions resulting in increase of hopping distance and therefore increase in activation energies with doping. Similar results have been reported for the activation energies of Fe, Ag, Gd and Y doped misfit layered cobaltites. 41,55,56

Hall effect measurements were carried out at room temperature for all samples, to determine the carrier concentration and their mobility as a function of dopant. It has been observed that carrier concentration ($n_{300 \text{ K}}$) initially increases from 5.12 × 10^{19} cm⁻³ (x = 0.0) to 6.59 × 10^{19} cm⁻³ (x = 0.025) with doping

and then decreases again to $4.48 \times 10^{19} \text{ cm}^{-3}$ (x = 0.075) with further increase in doping content as shown in Fig. 6. This increase in carrier concentration at low doping level is probably due to the substitution of Na⁺ for Ca²⁺ ions in C-349 system which results in increase of the number of hole carriers. With further increase in doping content (x), structural distortions and electron-doping like behavior of W⁶⁺ ions, due to the higher valence state of W⁶⁺ than Co³⁺ and Co⁴⁺ ions, start to dominate and result in decrease of carrier concentration. The carrier mobilities ($\mu_{300 \text{ K}}$) also follow the same trend and decrease to a value of 0.65 cm² V⁻¹ s⁻¹ with increase in doping after showing the maximum value for x = 0.025 sample (Table 2). These trends in $n_{300 \text{ K}}$ and $\mu_{300 \text{ K}}$ together with the larger grain sizes (Table 2) of Na and W dual doped samples can be used to explain the electrical resistivity of these materials. With the largest values of $n_{300~\rm K}$, $\mu_{300~\rm K}$ and grain sizes, the x=0.025sample has the lowest value of electrical resistivity and then ρ increases with increase in doping according to the equation: $1/\rho$

Fig. 7(a) shows the temperature dependence of thermopower (S) of the $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ samples. The sign of S is positive for all samples suggesting that holes are the majority charge carriers. The values of S increase with increase in temperature for all samples. It is also evident from Fig. 7(a) (inset) that thermopower values increase with increase in doping content (x). The maximum value of 216 μ V K⁻¹ at 1000 K for x = 0.075 sample is higher than previously reported S values for Na doped C-349 system (187 μV K⁻¹) at this temperature. ^{25,40} As discussed above, x = 0.025 sample shows the largest values of $n_{300 \text{ K}}$ and $\mu_{300 \text{ K}}$, and then values of these quantities decrease with further increase in doping. This is consistent with the observed behavior of S with doping in our samples. ^{26,28} The contribution of carrier concentration and carrier mobility, $\mu(\varepsilon)$ in describing S is given by the Mott's formula (originated from the Sommerfeld expansion).57

$$S(T) = \frac{\pi^2 k_{\rm B}^2 T}{3e} \left[\frac{\partial (\ln(\sigma(\varepsilon)))}{\partial \varepsilon} \right]_{\varepsilon = \varepsilon_{\rm B}}$$
(3)

By using $[\sigma = en\mu(\varepsilon)]$ in eqn (3), we can get:

$$S(T) = \frac{C_{\rm e}}{n} + \frac{\pi^2 k_{\rm B}^2 T}{3e} \left[\frac{\partial \ln \mu(\varepsilon)}{\partial \varepsilon} \right]_{\varepsilon = \varepsilon_{\rm E}} \tag{4}$$

where $C_{\rm e}=(\pi^2k_{\rm B}{}^2T/3e)\Psi(\varepsilon)$ and $n,~\mu(\varepsilon)~C_{\rm e}$ and $\Psi(\varepsilon)$ are the carrier concentration, energy correlated carrier mobility, electronic specific heat and density of state (DOS), respectively. There are three possible reasons associated with this increase in

S values: (1) the Drude model predicts that first term $\left(\frac{C_e}{n}\right)$ in above equation is dominant.⁵⁸ In Na and W dual doped samples, carrier concentration (*n*) decreases with increase in doping (*x*) and therefore thermopower (*S*) increases. However, x = 0.0 sample does not follow this trend suggesting that the electronic specific heat (C_e) and second term in above equation are the dominated factors here. Wang *et al.*, reported that Fe doping in C-349 system increases the carrier concentration (*n*)

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7.0 32.0 $- \star - n_{300K}$ $- \bullet - \rho_{300K}$ 28.0 6.0 $n_{300K} (10^{17} \text{ cm}^{-3})$ 5.5 5.0 20.0 4.5 16.0 0.025 0.050 0.075 0.000 **Doping Content (x)**

Fig. 6 Room temperature carrier concentration ($n_{300 \text{ K}}$) and electrical resistivity ($\rho_{300 \text{ K}}$) as a function of doping (x) for Ca_{3-2x}Na_{2x}Co_{4-x}W_xO₉ (0 $\leq x \leq 0.075$) samples

and the electronic specific heat (C_e) , but the effect of C_e dominates over n which results in larger S values for doped samples.⁵⁹ (2) We could assume that slope of the density of states at Fermi level is the main contribution to the second part of the above equation for undoped sample. (3) Partial substitution of W⁶⁺ for Co³⁺/Co⁴⁺ ions decreases hole carriers and thus results in an increase of thermopower.

According to the Pisarenko relation for degenerated semiconductors:

$$|S| = \frac{8\pi^2 k_B^2 T}{3qh^2} m^* \left(\frac{\pi}{3n}\right)^{2/3} \tag{5}$$

where $k_{\rm B}$, h, q and m^* are the Boltzmann constant, Plank's constant, unit charge of electron and effective mass of carriers respectively. We have calculated a value of $m^*/m_e \sim 0.9$ for all samples by plotting room temperature S values vs. $n^{-2/3}$ as shown in inset of Fig. 5(b). We can apply a simple parabolic band model by using the measured n and estimated m^* values as described by the following equations:60

$$F_{1/2}(\xi) = \int_0^\infty \frac{x^{\lambda} dx}{1 + \exp(x - \xi)}$$
 (6)

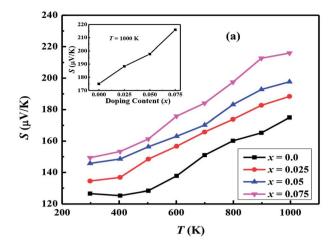
$$S = -\frac{k_{\rm B}}{q} \left[\frac{(2+\lambda)F_{\lambda} + 1}{(1+\lambda)F_{\lambda}} - \xi \right] \tag{7}$$

$$n = 4\pi \left(\frac{2m^*k_{\rm B}T}{h^2}\right)^{2/3} F_{1/2} \tag{8}$$

where $F_{1/2}(\xi)$ is the Fermi integral, ξ is the reduced electrochemical potential, λ is a scattering parameter and its value is taken 0 for acoustic phonon scattering, 1 for optical phonons scattering, and 2 for ionized impurity scattering.60 The calculated S values at room temperature as a function of carrier concentration (n) are shown in Fig. 7(b). Three different scattering mechanisms are represented by three straight lines in this plot. The measured and calculated values of S match very well when we take $\lambda = 0$, which suggests that the acoustic phonon scattering is the dominant scattering mechanism for all

We have used the electrical resistivity and thermopower values to calculate the thermoelectric power factor PF = S^2/ρ for all samples as shown in Fig. 8. The PF values increase with increase in temperature for all samples due to increase of thermopower with temperature. We can also see from Fig. 8 that PF values are significantly improved with Na and W dual doping in C-349 system. Among all doped samples, x = 0.025 sample exhibits the highest PF of $2.71 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$ at 1000 K which is about 2.3 times more than PF, 1.27×10^{-4} W m⁻¹ K⁻², of undoped sample. The PF obtained in this work is higher than the previously reported value of $\sim 2.1 \times 10^{-4} \, \mathrm{W m^{-1} K^{-2}}$ at 1073

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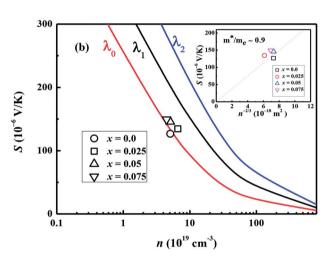


Fig. 7 (a) Thermopower (S) for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples as a function of temperature; inset shows doping content (x) dependence of S at 1000 K. (b) Thermopower (S) plotted as a function of carrier concentration (n); solid colored lines are the calculated values for ($\lambda = 0$, 1 & 2) representing electron scattering by acoustic phonons, optical phonons and ionized impurities respectively. Inset: plot of S vs. ($n^{-2/3}$); diagonal line corresponding to the Pisarenko relation with $m^*/m_e \sim 0.9$.

K for Ca₃Co_{3,97}Cu_{0.03}O₉ sample prepared by the conventional solid state reaction method.⁶¹

3.2.1. Thermal conductivity. The temperature dependent total thermal conductivity (κ_{Total}) for $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$ samples is shown in Fig. 9(a). We can clearly see that $\kappa(T)$ decreases with increase in temperature for all samples in the measured temperature range. For x=0.0 sample, measured value of κ at 1000 K is 1.36 W m⁻¹ K⁻¹ and it decreases to 1.26 W m⁻¹ K⁻¹ for x=0.025 sample. On further increase in doping, $\kappa_{1000~K}$ slightly increases again but its value remains lower than the pristine C-349 system. In order to understand the observed changes, we have investigated the contribution of electronic (κ_{el}) and lattice $(\kappa_{\text{Lattice}})$ parts of the thermal conductivity, separately. Fig. 9(b) shows the values of κ_{el} as determined from the experimentally measured ρ values by using the

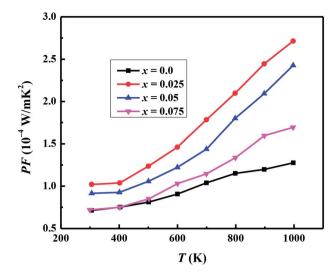


Fig. 8 Power factor (PF) for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ (0 $\leq x \leq$ 0.075) samples as a function of temperature.

Wiedemann–Franz law ($\kappa_{\rm el} = LT/\rho$), where L is the Lorentz number and its value is $2.44 \times 10^{-8}\,{\rm W}\,\Omega\,{\rm K}^{-2}$ for free electrons.³ The values of $\kappa_{\rm Lattice}$ were calculated using the relation $\kappa_{\rm Lattice} = \kappa_{\rm Total} - \kappa_{\rm el}$ and are shown in Fig. 9(c). It is evident from plot that $\kappa_{\rm Lattice}$, and not $\kappa_{\rm el}$, is the major contributing factor to total thermal conductivity of our samples. Hence, changes in $\kappa_{\rm Total}$ with increase in doping content (x) are mainly originated from the changes in $\kappa_{\rm Lattice}$.³³ We can attribute these changes in $\kappa_{\rm Lattice}$ to the larger ionic radius of W⁶⁺ than Co³+/Co⁴+ ions resulting in structural distortions, and therefore increase in phonon scattering. However, we cannot rule out some other unexplained microstructural aspects of these materials that can also be responsible for irregular behavior in thermal conductivity of doped samples.

3.2.2. Figure of merit. The thermoelectric figure of merit $(zT = S^2/\kappa\rho)$ for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ samples as a function of temperature and doping content (x) are shown in Fig. 10. It is evident that zT values of doped samples are significantly higher than the pristine C-349 system. The x = 0.025 has the highest zT value of 0.21 at 1000 K among all samples, which is about 2.3 times higher than zT value of the undoped sample. This increase in zT value is due to increase in Seebeck coefficient, and decrease in electrical resistivity and thermal conductivity of this sample. zT values of other doped samples are also reasonably good as listed in Table 2. As a comparison, zT value of our x = 0.025 sample is comparable or slightly better than previously reported results of Na doped Ca2.5- $Na_{0.5}Co_4O_9$ ($zT_{1000 \text{ K}} = 0.18$),²⁵ Bi and Na dual doped C-349 system $(zT_{1073 \text{ K}} = 0.18)$,62 $Ca_{2.8}La_{0.2}Co_{3.8}Cu_{0.2}O_9$ $(zT_{773 \text{ K}} =$ 0.203), 40 Bi and Na substituted Ca₃Co₄O₉ system ($zT_{1000 \text{ K}} =$ 0.32),²⁶ Gd and Y dual doped $Ca_{2.7}Gd_{0.15}Y_{0.15}Co_4O_{9+\delta}$ ($zT_{973 \text{ K}} =$ 0.26),⁶³ NaF doped $Ca_{3-x}Na_xCo_4O_{9-x}F_x$ ($zT_{873\ K}=0.13$)⁶⁴ and $Ca_{2.9}Y_{0.1}Co_{3.97}Fe_{0.03}O_9$ ($zT_{1000 \text{ K}} = 0.22$) compound.⁴² It has been observed that electrical resistivity of our samples is still higher than most of the previously reported results, and therefore zT values of these materials are moderate. We believe

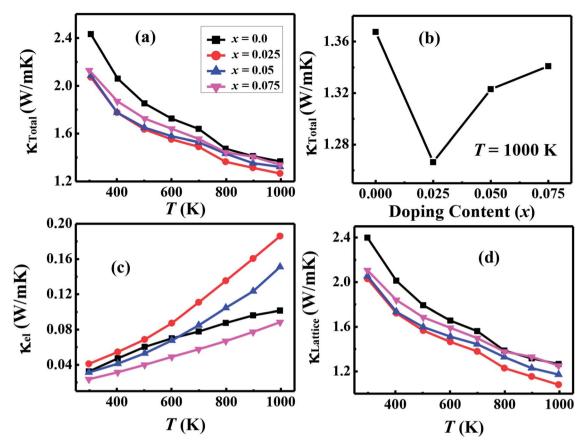


Fig. 9 (a) Total thermal conductivity ($\kappa_{Total} = \kappa_{el} + \kappa_{Lattice}$); (b) doping content (x) dependence of κ_{Total} at 1000 K; (c) electronic part of thermal conductivity (κ_{el}) and (d) lattice part of thermal conductivity ($\kappa_{Lattice}$) for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ (0 $\leq x \leq$ 0.075) samples as a function of temperature.

that zT values of these samples can be further improved by preparing more compact materials under optimized synthesis conditions.

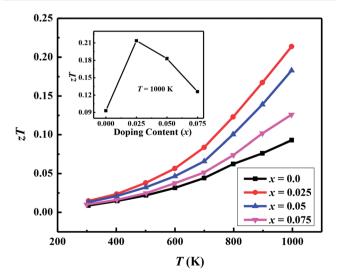


Fig. 10 Thermoelectric figure of merit (zT) for $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ ($0 \le x \le 0.075$) samples as a function of temperature; inset shows doping content (x) dependence of zT at 1000 K.

4. Conclusion

Polycrystalline samples of $Ca_{3-2x}Na_{2x}Co_{4-x}W_xO_9$ (0 $\leq x \leq$ 0.075) have been synthesized by the conventional solid state reaction method. Powder X-ray diffraction data revealed that Na⁺ and W⁶⁺ ions enter into the Ca₂CoO₃ and CoO₂ layers of Ca₃Co₄O₉ system respectively. High resolution XPS data showed that the average valence state of Co in our samples is between 3+ and 4+. Significant improvements in ρ , S and κ values of Na and W dual doped samples have been observed. These results are also supported by the carrier concentrations (n) and carrier mobility (μ) as confirmed by the Hall effect measurements. The observed power factor (PF) and thermoelectric figure of merit (zT) of $2.71 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$ and 0.21 respectively at 1000 K for x = 0.025 sample are comparable or slightly higher than most of the reported results of C-349 based materials, prepared by the conventional solid state reaction method. These results show that Na and W dual doping is an effective route for improving thermoelectric properties of Ca₃Co₄O₉ system.

Conflicts of interest

There are no conflicts to declare.

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